

# Mechanisms of High Energy Charged Particles Beam Deflection by bent crystals. Analogies

#### N.F. Shul'ga, V.I. Truten', I.V. Kirillin

Akhiezer Institute for Theoretical Physics of NNC KIPT, Kharkov, Ukraine shulga@kipt.kharkov.ua

- •Planar channeling in a bent crystal
- Volume reflection
- Stochastic mechanism
- •CERN Experiments

#### Mechanisms of Charged Particles Motion near <100> Axis



- a) Hyperchanneling (e<sup>+</sup>, e<sup>-</sup>)
- b) Stochastic multiple scattering
- c) Planar channeling
- d) Above barrier motion  $\epsilon_{\perp} \sim U_{plmax}$
- e) Above barrier motion  $\epsilon_{\perp} >> U_{plmax}$



# Beam Deflection of fast Charged Particles due to Plane Channeling Effect in Bent Crystal

E.Tsyganov (1976)





# "Volume reflection" effect

A. Taratin, S. Vorobiev 1987



#### **Stochastic Mechanism of Beam Deflection**

A.Greenenko, N. Shul'ga (1991)





#### Plane Channeling (Regular Motion) Lindhard (1965)



*p*<sub>z</sub>=const≈p  $\ddot{x} = -\frac{1}{E}\frac{\partial}{\partial x}U_{p}\left(x\right)$  $\varepsilon_{\perp p} = \frac{E \dot{x}^2}{2} + U_p(x)$ 





# The Motion of Relativistic Particle in Central Field of Bent Crystal Planes



A. Akhiezer, N.Shul'ga, A.Greenenko et al., Sov.Phys. Usp. 1995 J. Ellison, Nucl. Phys. B 206 (1982) 205

# **Critical Radius of Channeling in Bent Crystal**



$$\begin{aligned} U_{eff}(x) &= U_p(x) - x \frac{E}{R} \\ \frac{\partial U_{eff}(x)}{\partial x} \bigg|_{x=d/2} &= 0 \end{aligned}$$

$$R_c = d \frac{E}{2U_{\text{max}}}$$

 $E = 100 \, GeV, \quad U_{\text{max}} = 20 \, eV, \quad d = 0.2 \, nm, \implies R_c = 25 \, cm$ 

#### Beam Reflection from Bent Crystal Planes

N.F. Shul'ga, V.I. Truten', V.V. Boyko, 2009



$$r = R + x, \qquad b = R + \Delta$$
$$R >> x, \quad R >> \Delta, \quad E >> U_p$$

Analogy with scattering in central field

$$\vartheta(b) = \pi - 2M \int_{r_0}^{\infty} \frac{dr/r^2}{\sqrt{\left(\varepsilon - U_p\right)^2 - M^2/r^2 - m^2}}, \qquad M = pb$$

## Scattering on one bent crystal plane



**e**<sup>+</sup>

e

# Scattering by Nanotube

N.Shul'ga, V.Truten', (2000)









X. Artru et al., Phys. Reports, 2005

## Potential for Beam Reflection by Bent Crystal Planes



$$\vartheta(b) = \pi - 2bv\sqrt{E} \int_{r_0}^{\infty} \frac{dr/r^2}{\sqrt{E - U_{eff}(r,b)}}$$
$$U_{eff}(r,\Delta) = E + 2U(x) + 2E(\Delta - x)/R$$



Condition for bending:

$$\alpha = \frac{4U_0}{E} \frac{R}{d} >> 1$$

#### **Deflection Functions for Beam Reflection in Crystal**

N.F. Shul'ga, V.I. Truten', V.V. Boyko, 2009





Motion of a fast positively charged particle (a) in the field of a single atomic string and (b) in the periodic field of atomic strings of a diamond crystal in the plane orthogonal to the <100> axis

#### Scattering by Atomic String N.Shul'ga, S.Fomin, V.Truten', (1984)



#### Multiple Scattering on Atomic strings



V. Beloshitskii, M. Kumakhov (1973),  $\psi < \psi_c$ N. Shul'ga, V. Truten', S. Fomin (1982),  $\psi > \psi_c$ 

# Dynamical Chaos at Multiple Scattering for e $z = \psi / \psi_c$



A. Akhiezer, N Shul'ga, V. Truten', Physics Reports, 1991

# Multiple Scattering in Oriented Crystal (simulation)



Si, <111>, E=450 GeV



#### **Stochastic Mechanism of Beam Deflection**

A. Greenenko, N. Shul'ga (1991)





A.A. Greenenko, N.F. Shul'ga, NIM B 173 (2001) 178

#### Beam Deflection in Bent Crystal (simulation)



# Angular Distribution of 400 GeV Protons after Passing 2 mm of Bent Si Crystal with R=40 m



CERN experiment

Simulation results

W. Scandale et al. Phys. Rev. Lett. 101 (2008), 164801 21

# Angular Distribution of 150 GeV π<sup>-</sup>-mesons after Passing 1.172 mm of Bent Si Crystal with R=40 m



#### Simulation results

W. Scandale et al. Physics Letters B 680 (2009) 301-304 22

#### Initial Conditions for Beam Deflection by Bent Crystals



# Stochastic Mechanism of Beam Deflection $\psi_x \approx \psi_y < \psi_c$





# Trajectories in Stochastic Mechanism of Particles Deflection in a Bent Crystal for E=300 GeV, R=100 m





#### Beam Deflection in a Bent Crystal (stochastic mechanism)



## Beam Deflection in a Bent Crystal (stochastic mechanism)

## **Beams Initial Conditions**

**→** X

#### **Stochastic Mechanism**



У

 $\psi_x \approx \psi_v < \psi_c$ 





 $\psi_x < \theta_p, \quad \psi_y >> \psi_c$ 

#### Beam Deflection in a Bent Crystal (plane channeling) e+, E=400 GeV, R=40 m, 200 particles, $\psi_x \approx 0$ , $\psi_v \approx 10 \psi_c$ 0 cm 0.2 cm 0.4 cm 400 $e^+$ 350 300 250 200 $\Theta_{y}, \mu rad$ 0.6 cm 0.8 cm 1 cm 400 350 300 250 200 100 150 200 250 50 100 150 200 250 50 100 150 200 250 50 0 0 0 $\Theta_x, \mu rad$

# Beam Deflection in a Bent Crystal (plane channeling)



# **Beams Initial Conditions**

Ζ

**→** X

#### Stochastic Mechanism



y**,** 

 $\psi_x \approx \psi_y < \psi_c$ 

**Volume Reflection** 





# Beam Deflection in a Bent Crystal (volume reflection)



# CONCLUSIONS (analogies)

Bent crystal	Central field	
Plane channelling	Finite motion in the central field, precession,	
Volume reflection	Scattering in the central field, orbiting,	
Stochastic	Dynamical chaos Multiple scattering	

## CONCLUSIONS (efficiency)

Plane channelling	<i>e</i> <sup>+</sup> <i>e</i> <sup>-</sup> -?	$R > a \frac{\varepsilon}{U_0}$	$\theta >> \theta_p$
Volume reflection	e <sup>+</sup> e <sup>-</sup> − ?	$R >> a \frac{\varepsilon}{U_0}$	$\theta \le 2 \theta_p$
Stochastic	e <sup>+</sup> e <sup>-</sup> - !!!	$\frac{l_{\perp}}{R\psi_c} \frac{L}{R\psi_c} < 1$	$\theta \sim 10 \psi_c$

# Thank You for Your Attention



$$\theta_{out} \approx 2\theta_{p-\nu} \qquad \qquad \theta_{out} \approx 2\left(\theta_{p-s_1}\sin\left(\alpha_{s_1}\right) + \theta_{p-s_2}\sin\left(\alpha_{s_2}\right) + \theta_{p-\nu}\right)$$